

Description

The 60N06 uses advanced trench technology and design to provide excellent $R_{\text{DS}(\text{ON})}$ with low gate charge. It can be used in a wide variety of applications.

III DS

TO-220H

General Features

 $V_{DS} = 60V, I_{D} = 60A$

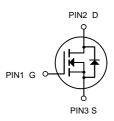
 $R_{DS(ON)}$ < 20m Ω @ V_{GS} =10V

Application

High efficiency switch mode power supplies

Power factor correction

Electronic lamp ballast



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Units Tube
60N06	TO-220H	HXY 60N06 YYYY	50

Absolute Maximum Ratings@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	60	V
VGS	Gate-Source Voltage	<u>+</u> 20	V
I _D @T _C =25°C	Drain Current	60	А
IDM	Pulsed Drain Current ¹	240	А
P _D @T _C =25°C	Total Power Dissipation	120	W
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C



Electrical Characteristics (T_C=25 [°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage (Note 1)	BV _{DSS}	V _{GS} =0V I _D =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	60	68	-	nA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	2.0	-	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =25A	-	17	20	mΩ
Forward Transconductance	G FS	V _{DS} =30V,I _D =40A	15	-	-	S
Dynamic Characteristics			•			
Input Capacitance	C _{lss}	V _{DS} =25V,V _{GS} =0V,	-	4050	-	PF
Output Capacitance	Coss		-	430	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	110	-	PF
Switching Characteristics			•			
Turn-on Delay Time	t _{d(on)}		-	60	-	nS
Turn-on Rise Time	t _r	$V_{DD} = 30V, I_{D} = 40A$	-	185	-	nS
Turn-Off Delay Time	t _{d(off)}	R_G =50 Ω (Note 2)	-	75	-	nS
Turn-Off Fall Time	t _f		-	60	-	nS
Total Gate Charge	Qg	\/ 00\/ L 40A	-	39	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=30V,I_{D}=40A,$ $V_{GS}=10V^{(Note 2)}$	-	9.3	-	nC
Gate-Drain Charge	Q _{gd}	VGS-IUV	-	13	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =60A	-		1.5	V
Diode Forward Current (Note 2)	Is		-	-	60	Α

Notes:

^{1.} Repetitive Rating: Pulse width limited by maximum junction temperature.

^{2.} Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2\%$.



Typical Electrical

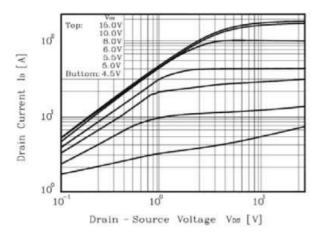


Figure 1. On Region Characteristics

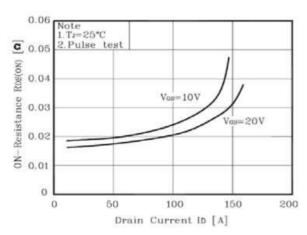


Figure 3. On Resistance Variation vs Drain Current and Gate Voltage

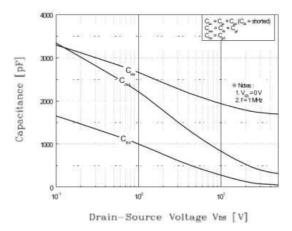


Figure 5. Capacitance Characteristics

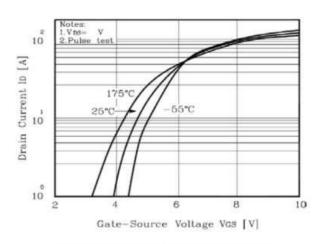


Figure 2. Transfer Characteristics

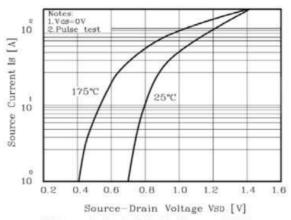


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

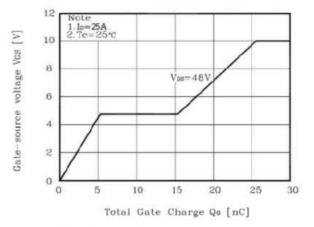


Figure 6. Gate Charge Characteristics

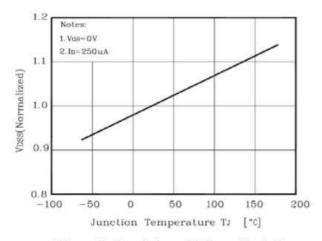


Figure 7. Breakdown Voltage Variation vs Temperature

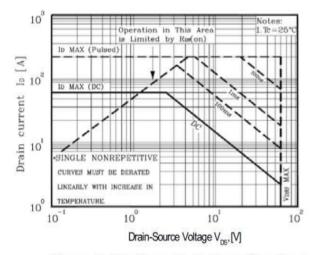


Figure 9. Maximum Safe Operating Area

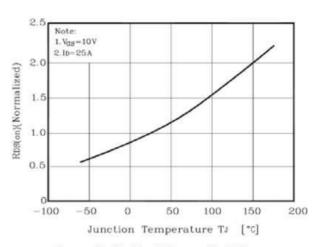


Figure 8. On-Resistance Variation vs Temperature

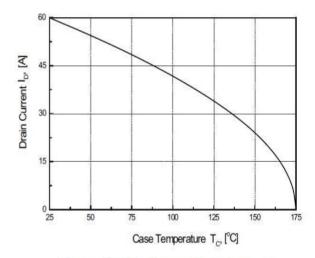


Figure 10. Maximum Drain Current vs Case Temperature

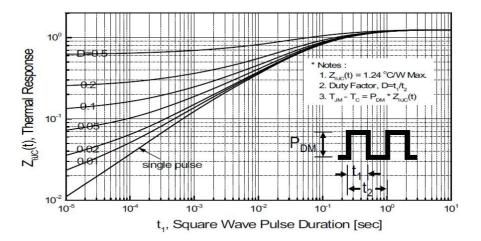
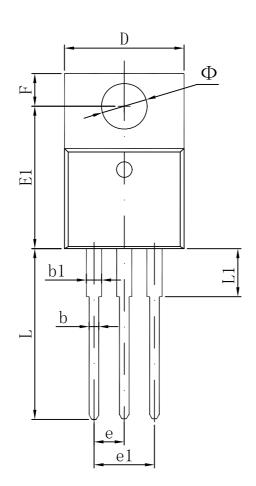
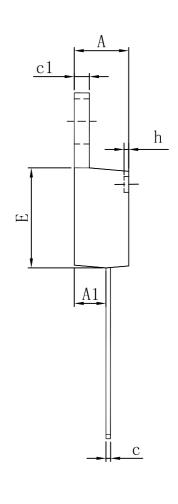


Figure 11. Transient Thermal Response Curve



Package Information TO-220H





Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	4.470	4.670	0.176	0.184	
A1	2.520	2.820	0.099	0.111	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
Е	8.500	8.900	0.335	0.350	
E1	12.060	12.460	0.475	0.491	
е	2.540 TYP		0.100 TYP		
e1	4.980	5.180	0.196	0.204	
F	2.590	2.890	0.102	0.114	
h	0.000	0.300	0.000	0.012	
L	13.400	13.800	0.528	0.543	
L1	3.560	3.960	0.140	0.156	
Ф	3.735	3.935	0.147	0.155	

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